

Features

- 100% EAS Guaranteed
- Green Device Available
- Super Low RDS(ON)
- Advanced high cell density SGT Technology

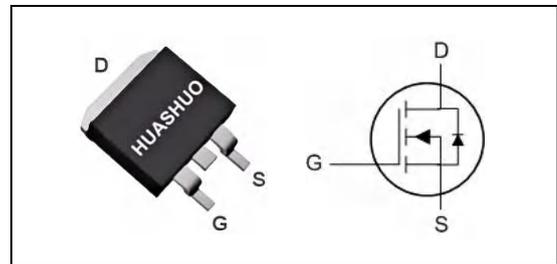
Product Summary

V_{DS}	150	V
$R_{DS(ON),typ}$	4.0	m Ω
I_D	190	A

Applications

- MOTOR Driver.
- UPS.
- Power Tools.
- Synchronous Rectification in SMPS.

TO-263 Pin Configuration



Absolute Maximum Ratings

Symbol	Parameter	Rating	Units
V_{DS}	Drain-Source Voltage	150	V
V_{GS}	Gate-Source Voltage	± 20	V
$I_D@T_C=25^\circ C$	Continuous Drain Current, $V_{GS} @ 10V^{1,6}$	190	A
$I_D@T_C=100^\circ C$	Continuous Drain Current, $V_{GS} @ 10V^{1,6}$	135	A
I_{DM}	Pulsed Drain Current ²	760	A
EAS	Single Pulse Avalanche Energy ³	890	mJ
$P_D@T_C=25^\circ C$	Total Power Dissipation ⁴	410	W
T_{STG}	Storage Temperature Range	-55 to 150	$^\circ C$
T_J	Operating Junction Temperature Range	-55 to 150	$^\circ C$

Thermal Data

Symbol	Parameter	Typ.	Max.	Unit
$R_{\theta JA}$	Thermal Resistance Junction-ambient ¹	---	55	$^\circ C/W$
$R_{\theta JC}$	Thermal Resistance Junction-Case ¹	---	0.36	$^\circ C/W$

Electrical Characteristics (T_J=25 °C, unless otherwise noted)

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V, I _D =250uA	150	---	---	V
R _{DS(ON)}	Static Drain-Source On-Resistance ²	V _{GS} =10V, I _D =20A	---	4.0	5.0	mΩ
V _{GS(th)}	Gate Threshold Voltage	V _{GS} =V _{DS} , I _D =250uA	2.0	3.0	4.0	V
I _{DSS}	Drain-Source Leakage Current	V _{DS} =120V, V _{GS} =0V, T _J =25°C	---	---	1	uA
		V _{DS} =120V, V _{GS} =0V, T _J =55°C	---	---	5	
I _{GSS}	Gate-Source Leakage Current	V _{GS} =±20V, V _{DS} =0V	---	---	±100	nA
R _g	Gate Resistance	V _{DS} =0V, V _{GS} =0V, f=1MHz	---	4.9	---	Ω
Q _g	Total Gate Charge (10V)	V _{DS} =75V, V _{GS} =10V, I _D =20A	---	128	---	nC
Q _{gs}	Gate-Source Charge		---	83	---	
Q _{gd}	Gate-Drain Charge		---	44	---	
T _{d(on)}	Turn-On Delay Time	V _{DD} =75V, V _{GS} =10V, R _G =4.5Ω, RL=1Ω, I _D =20A	---	33	---	ns
T _r	Rise Time		---	68	---	
T _{d(off)}	Turn-Off Delay Time		---	85	---	
T _f	Fall Time		---	41	---	
C _{iss}	Input Capacitance	V _{DS} =75V, V _{GS} =0V, f=1MHz	---	8660	---	pF
C _{oss}	Output Capacitance		---	720	---	
C _{rss}	Reverse Transfer Capacitance		---	28	---	

Diode Characteristics

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
V _{SD}	Diode Forward Voltage ²	V _{GS} =0V, I _S =50A, T _J =25°C	---	---	1.1	V
t _{rr}	Reverse Recovery Time	IF=15A, dI/dt=100A/μs, T _J =25°C	---	118	---	nS
Q _{rr}	Reverse Recovery Charge		---	431	---	nC

Note :

- 1.The data tested by surface mounted on a 1 inch² FR-4 board with 2OZ copper.
- 2.The data tested by pulsed , pulse width ≤ 300us , duty cycle ≤ 2%
- 3.The Power Dissipation is limited by 150°C junction temperature.
- 4.The EAS data shows Max. rating . The test condition is V_{DD}=75V,V_{GS}=10V,L=0.3mH,I_{AS}=75A
- 5.The data is theoretically the same as I_D and I_{DM} , in real applications , should be limited by total power dissipation.
- 6.Package limitation Current.

Typical Characteristics

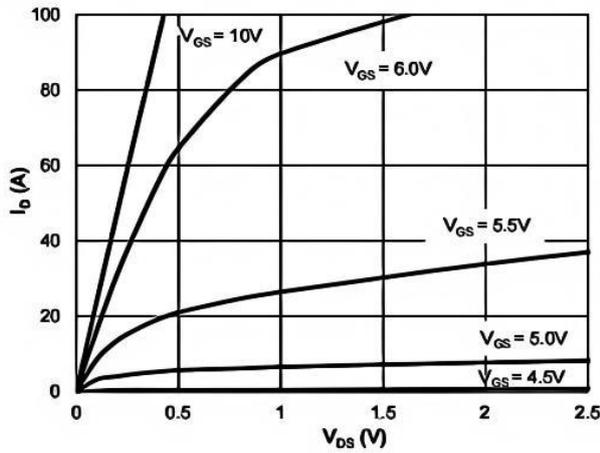


Figure 1: Saturation Characteristics

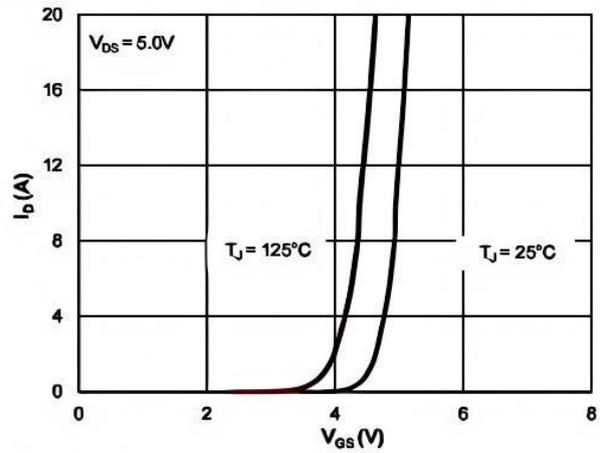


Figure 2: Transfer Characteristics

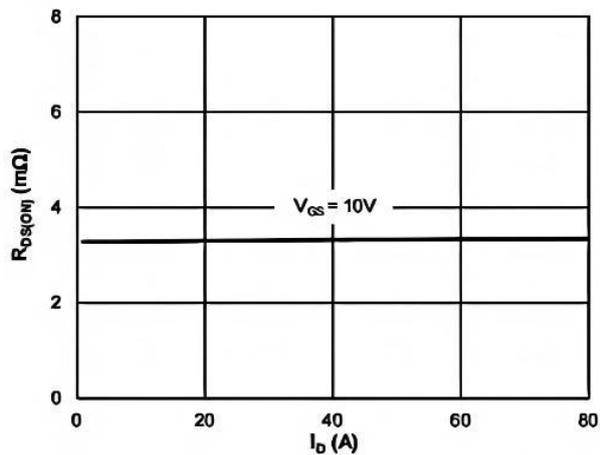


Figure 3: $R_{DS(ON)}$ vs. Drain Current

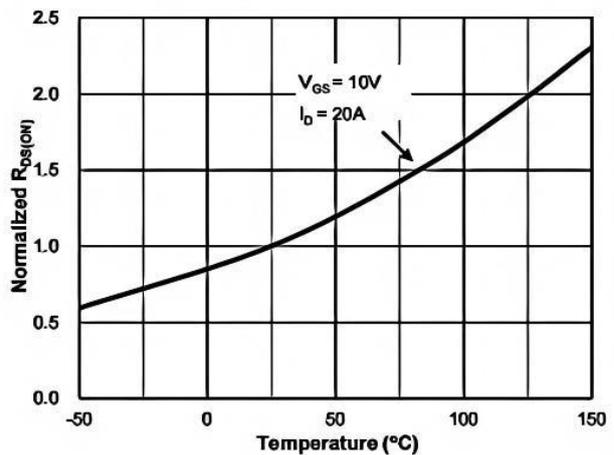


Figure 4: $R_{DS(ON)}$ vs. Junction Temperature

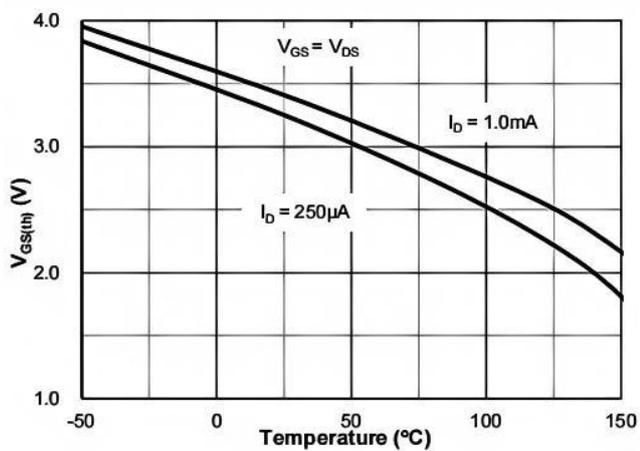


Figure 5: $V_{GS(th)}$ vs. Junction Temperature

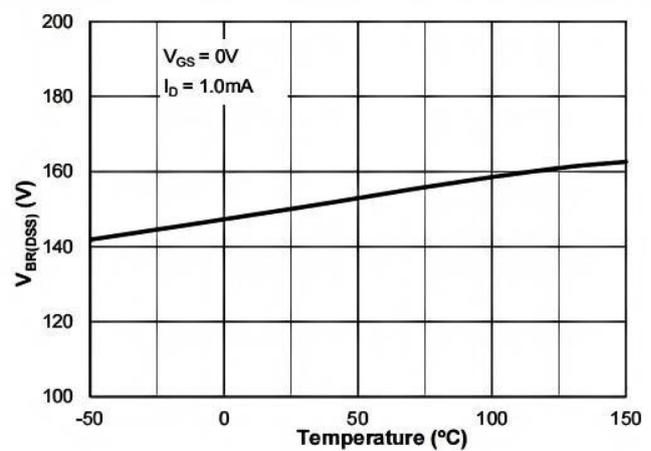


Figure 6: $V_{BR(DSS)}$ vs. Junction Temperature

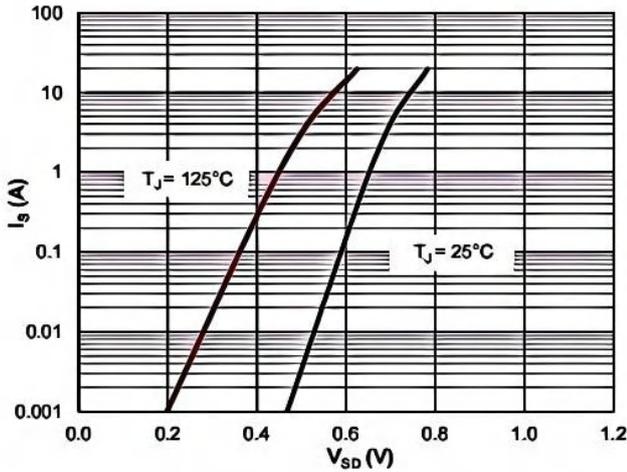


Figure 7: Body-Diode Characteristics

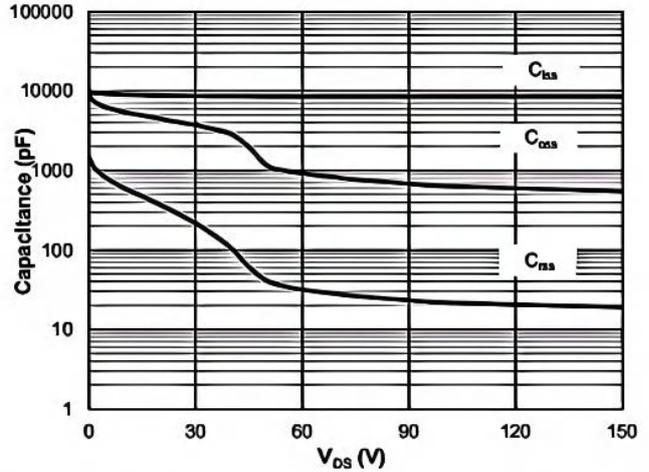


Figure 8: Capacitance Characteristics

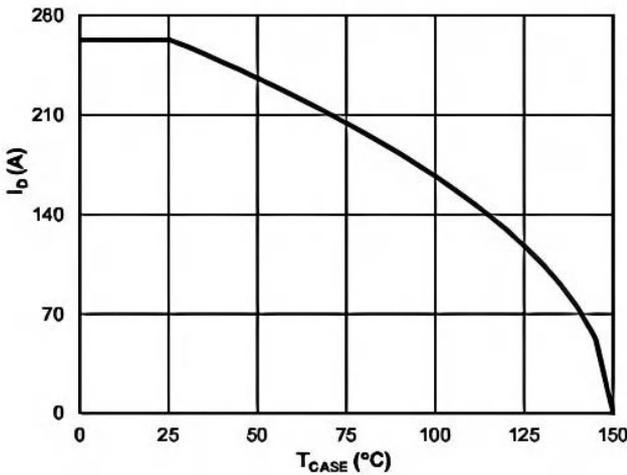


Figure 9: Current De-rating

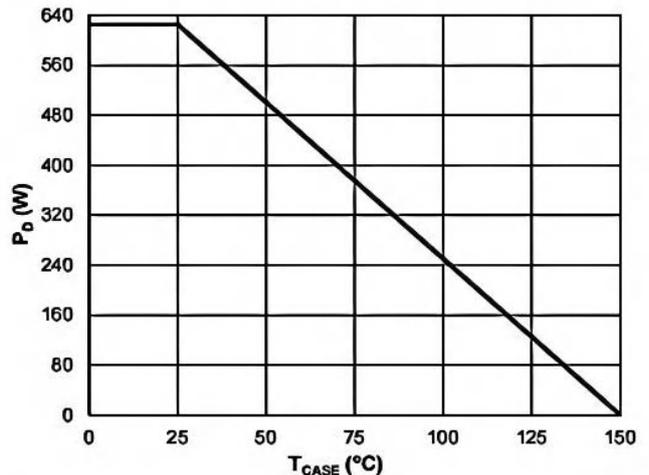


Figure 10: Power De-rating

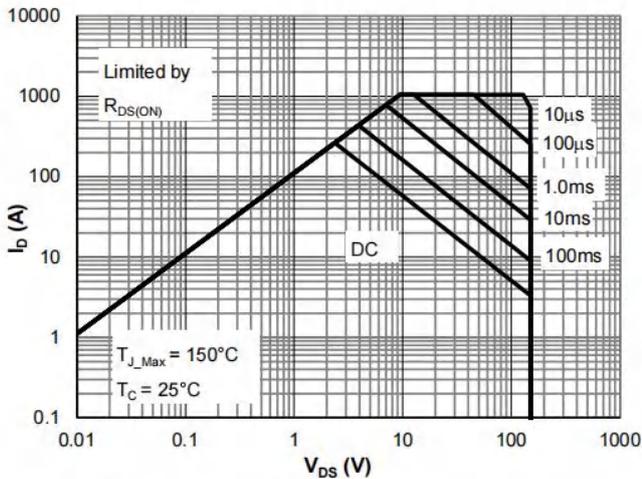


Figure 11: Maximum Safe Operating Area

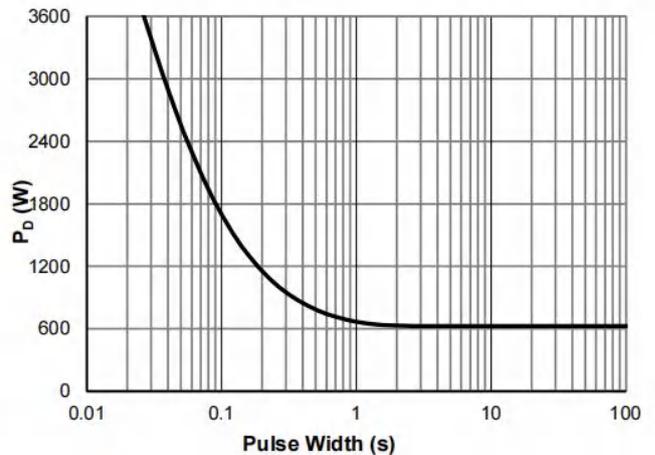


Figure 12: Single Pulse Power Rating, Junction-to-Case

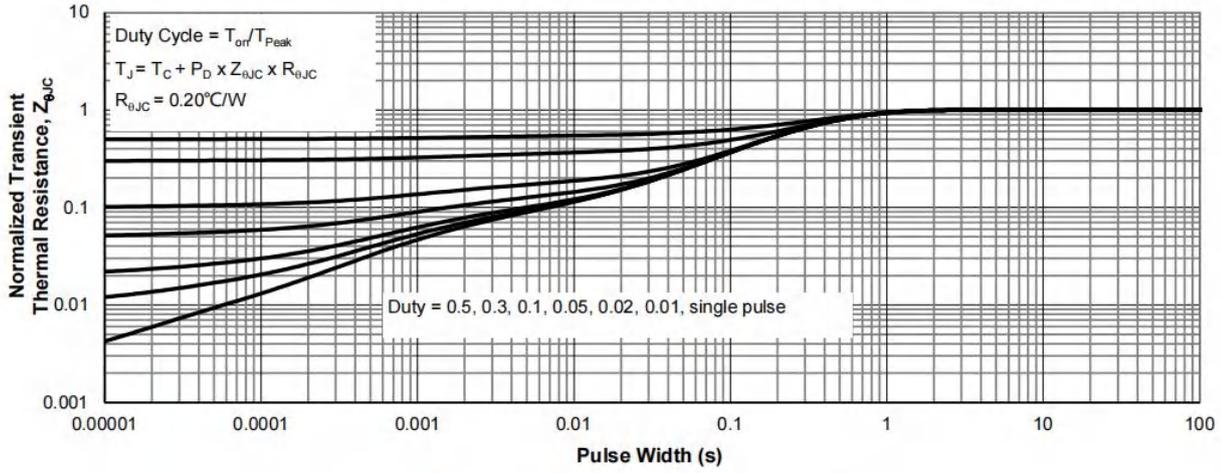
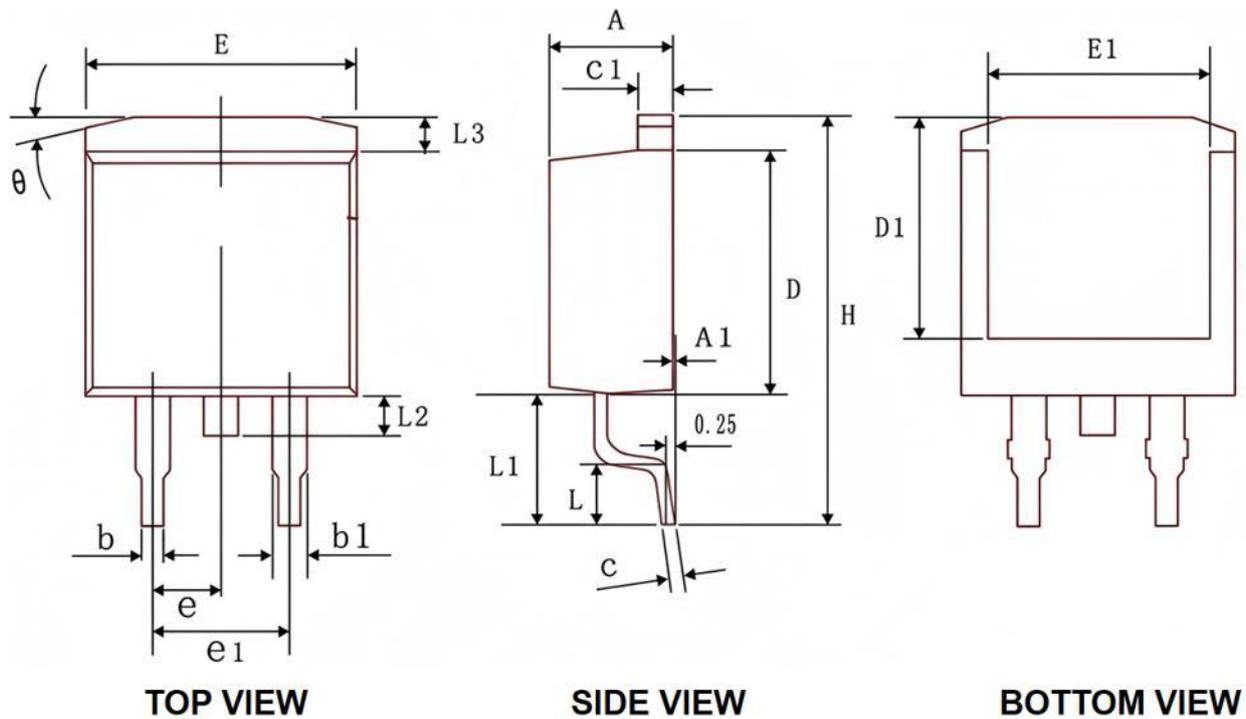


Figure 13: Normalized Maximum Transient Thermal Impedance

Ordering Information

Part Number	Package code	Packaging
HSH1502	TO-263	800/Tape&Reel

TO-263 Package Outline

COMMON DIMENSIONS(UNIT OF MEASURE - MM)

SYMBOL	MIN	NOM	MAX
A	4.37	4.57	4.77
A1	0.00	-	0.25
b	0.70	0.83	0.96
b1	1.00	1.24	1.47
C	0.35	0.45	0.55
C1	1.25	1.30	1.35
D	8.50	8.90	9.30
D1	7.50	8.00	8.50
H	14.7	15.20	15.7
E	9.80	10.08	10.4
E1	7.35	7.80	8.25
e1	4.93	5.08	5.23
L	2.00	2.30	2.60
L1	4.50	4.75	5.00
L2	1.30	1.53	1.75
L3	1.10	1.29	1.47
e	2.54 BSC		
θ	13°TYP		



HSH1502 Marking:

